

General purpose PIN diode

FEATURES

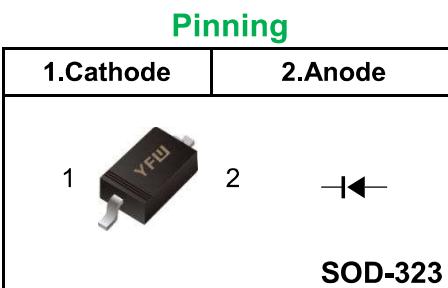
- ◆ Low diode capacitance
- ◆ Low diode forward resistance.

APPLICATIONS

- ◆ General RF applications.

DESCRIPTION

- ◆ General purpose PIN diode in a SOD323 small plastic SMD package.



Marking Code	
BAP50-03	A8

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage		—	50	V
I_F	continuous forward current		—	50	mA
P_{tot}	total power dissipation	$T_s = 90^\circ\text{C}$	—	500	mW
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-65	+150	°C

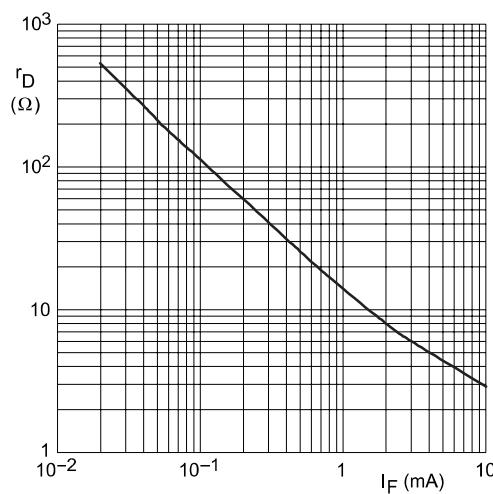
ELECTRICAL CHARACTERISTICS
 $T_j = 25^\circ\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	forward voltage	$I_F = 50 \text{ mA}$	—	0.95	1.1	V
V_R	reverse voltage	$I_R = 10 \mu\text{A}$	50	—	—	V
I_R	reverse current	$V_R = 50 \text{ V}$	—	—	100	nA
C_d	diode capacitance	$V_R = 0; f = 1 \text{ MHz}$	—	0.4	—	pF
		$V_R = 1 \text{ V}; f = 1 \text{ MHz}$	—	0.3	0.55	pF
		$V_R = 5 \text{ V}; f = 1 \text{ MHz}$	—	0.2	0.35	pF
r_D	diode forward resistance	$I_F = 0.5 \text{ mA}; f = 100 \text{ MHz}; \text{ note 1}$	—	25	40	Ω
		$I_F = 1 \text{ mA}; f = 100 \text{ MHz}; \text{ note 1}$	—	14	25	Ω
		$I_F = 10 \text{ mA}; f = 100 \text{ MHz}; \text{ note 1}$	—	3	5	Ω

Note 1. Guaranteed on AQL basis: inspection level S4, AQL 1.0.

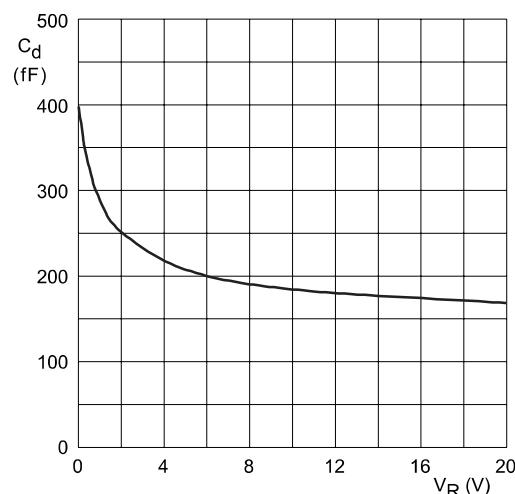
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
$R_{th,j-s}$	thermal resistance from junction to soldering point	85	K/W

GRAPHICAL DATA


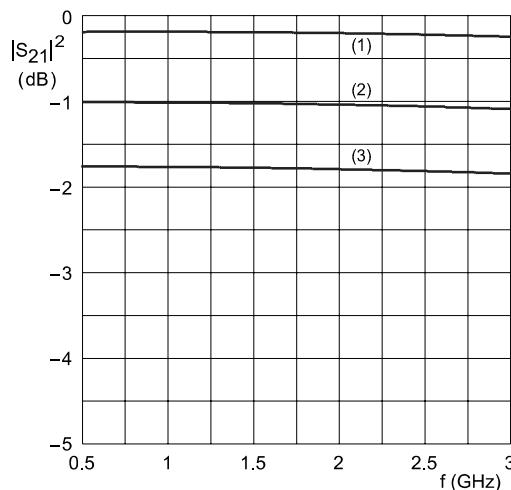
$f = 100 \text{ MHz}; T_j = 25^\circ\text{C}.$

Fig.2 Forward resistance as a function of forward current; typical values.



$f = 1 \text{ MHz}; T_j = 25^\circ\text{C}.$

Fig.3 Diode capacitance as a function of reverse voltage; typical values.

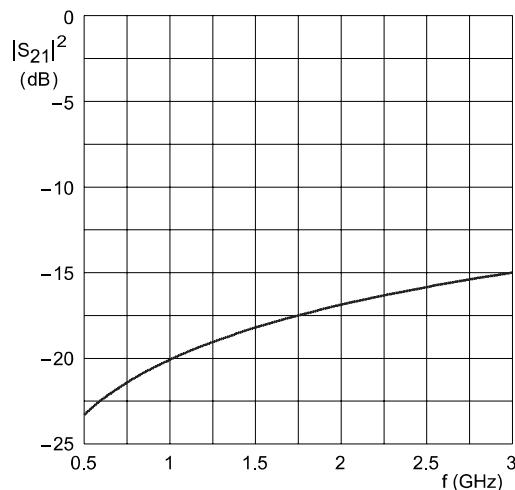


(1) $I_F = 10 \text{ mA}$. (2) $I_F = 1 \text{ mA}$. (3) $I_F = 0.5 \text{ mA}$.

Diode inserted in series with a 50Ω stripline circuit and biased via the analyzer Tee network.

$T_{\text{amb}} = 25^\circ\text{C}$.

Fig.4 Insertion loss ($|S_{21}|^2$) of the diode as a function of frequency; typical values.



Diode zero biased and inserted in series with a 50Ω stripline circuit.
 $T_{\text{amb}} = 25^\circ\text{C}$.

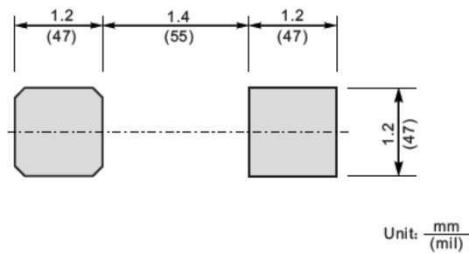
Fig.5 Isolation ($|S_{21}|^2$) of the diode as a function of frequency; typical values.

Ordering information

Package	Packing Description	Packing Quantity
SOD-323	Tape/Reel,7"reel	3000PCS/Reel 120000PCS/Carton

Package Dimensions
SOD-323

Dim.	Millimeter(mm)		mil	
	Min.	Max.	Min.	Max.
A	0.8	1.1	32	43
C	0.08	0.15	3.1	5.9
D	1.2	1.4	47	55
E	1.4	1.8	63	70
E1	2.55	2.75	100	108
b	0.25	0.4	9.8	16
L1	0.2	0.45	7.9	16
A1	-	0.2	-	8
∠	9°			

The recommended mounting pad size


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